HVU131

Silicon Epitaxial Planar Pin Diode for High Frequency Switching

HITACHI

ADE-208-239E(Z) Rev 5 Feb. 2000

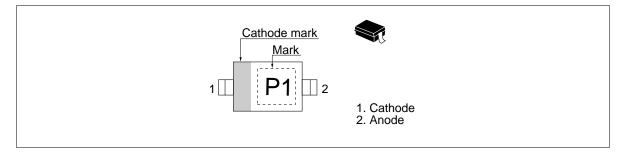
Features

- Low capacitance.(C=0.8pF max)
- Low forward resistance. (rf= 1.0Ω max)
- <u>U</u>ltra small <u>Resin Package</u> (URP) is suitable for surface mount design.

Ordering Information

| Туре No. | Laser Mark | Package Code |
|----------|------------|--------------|
| HVU131 | P1 | URP |

Outline





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Absolute Maximum Ratings (Ta = 25° C)

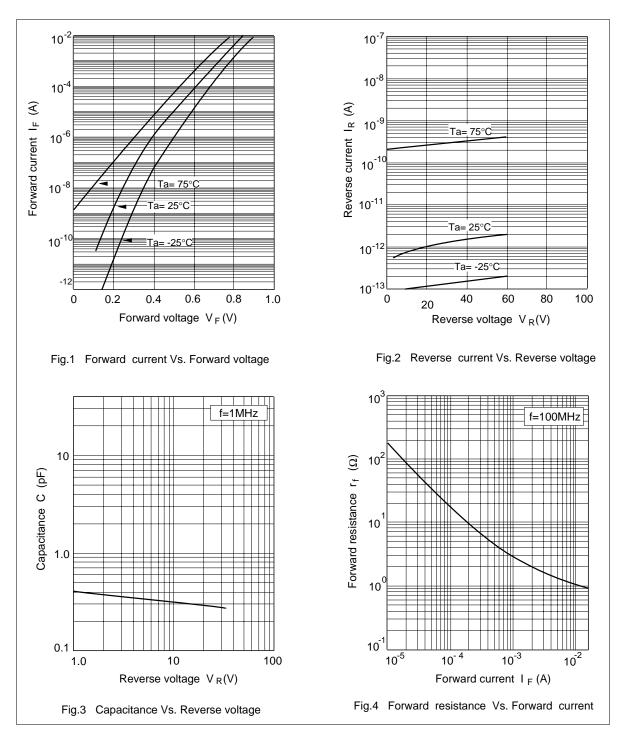
| Item | Symbol | Value | Unit | | |
|----------------------|-----------------|-------------|------|--|--|
| Peak reverse voltage | V _{RM} | 65 | V | | |
| Reverse voltage | V _R | 60 | V | | |
| Forward current | I _F | 100 | mA | | |
| Power dissipation | P _d | 150 | mW | | |
| Junction temperature | Тј | 125 | °C | | |
| Storage temperature | Tstg | -55 to +125 | °C | | |

Electrical Characteristics (Ta = 25° C)

| ltem | Symbol | Min | Тур | Мах | Unit | Test Condition |
|--------------------|----------------|-----|-----|-----|------|-------------------------------------|
| Reverse current | I _R | _ | _ | 0.1 | μΑ | $V_R = 60V$ |
| Forward voltage | V _F | | — | 1.0 | V | $I_F = 10 \text{ mA}$ |
| Capacitance | С | | — | 0.8 | pF | $V_{R} = 1V$, f = 1 MHz |
| Forward resistance | r _f | | | 1.0 | Ω | I _F = 10 mA, f = 100 MHz |

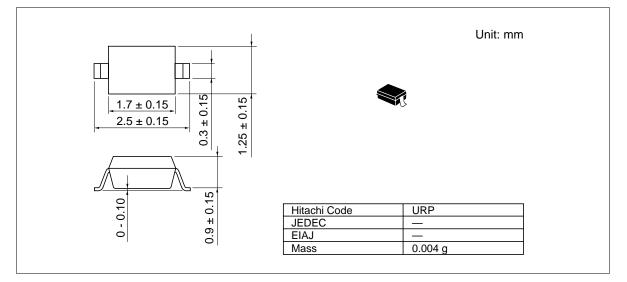
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Main Characteristic



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Package Dimensions



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